

Dual Wavelength SMD Type Infrared Emitter

Features

- Small double-end package
- Dual peak wavelength.
 (SIR=880nm, R=620nm)
- High reliability
- Good spectral matching to Si photo detector
- RoHS compliance

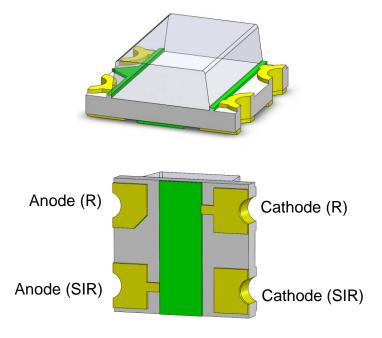
Applications

Infrared sensor

Description

The SRP1615X07-B20 is a GaAlAs infrared LED housed in a miniature SMD package. The device has a peak wavelength of 880nm and 620nm LED spectrally matched with phototransistor or photodiode.

Package Outline



Schematic





Absolute Maximum Rating at 25°C

Symbol	Parameters		Ratings	Units	Notes
I _F	Continuous Forward Current	SIR(880)	70	A	
IF.	Continuous Forward Current	R ₍₆₂₀₎	50	mA	
1	Dook Forward Current	SIR ₍₈₈₀₎	0.7	^	1
IFP	I _{FP} Peak Forward Current		0.1	A	'
V _R	Reverse Voltage		5	V	
Topr	Operating Temperature		-40 ~ +85	°C	
T _{stg}	Storage Temperature		-40 ~ +100	οС	
T _{sol}	Soldering Temperature		260	°C	2
D-	Power Dissipation at(or below) 25°C Free Air	SIR ₍₈₈₀₎	140	mW	
r _D	P _D Temperature		160	IIIVV	

Electro-Optical Characteristics TA = 25°C (unless otherwise specified)

Optical Characteristics (SIR₍₈₈₀₎)

Symbol	Parameters	Test Conditions	Min	Тур	Max	Units	Notes
la.	Radiant Intensity	I _F =20mA	1.4	2.4	-	mW/sr	
le		I _F =70mA	-	8.0	-	THVV/SI	
λр	Peak Wavelength	I _F =20mA	-	880	-	nm	
Δλ	Spectral Bandwidth	I _F =20mA	-	30	-	nm	
θ1/2	Angle of Half Intensity	I _F =20mA	-	±60	-	deg	

Optical Characteristics (R₍₆₂₀₎)

Symbol	Parameters	Test Conditions	Min	Тур	Max	Units	Notes
I.a.	Dedient laterality	I _F =20mA	1.4	2.6	-	mW/sr	
le	Radiant Intensity	I _F =50mA	-	6.0	-	THVV/SI	
lv	Luminous Intensity	I _F =20mA	-	730	-	mcd	
λр	Peak Wavelength	I _F =20mA	-	620	-	nm	
λd	Dominant Wavelength	I _F =20mA	-	614	-	nm	
Δλ	Spectral Bandwidth	I _F =20mA	-	15	-	nm	
θ1/2	Angle of Half Intensity	I _F =20mA	-	±60	-	deg	



Dual Wavelength SMD Type Infrared Emitter

Electrical Characteristics (SIR₍₈₈₀₎)

Symbol	Parameters	Test Conditions	Min	Тур	Max	Units	Notes
V Forward Valtage		I _F =20mA	1.20	1.40	1.7	V	
V _F	Forward Voltage	I _F =70mA	1.30	1.55	2.0	V	
I _R	Reverse Current	V _R =5V	-	-	10	μΑ	

Electrical Characteristics (R₍₆₂₀₎)

Symbol	Parameters	Test Conditions	Min	Тур	Max	Units	Notes
V Familiary Valtage		I _F =20mA	1.8	2.2	2.6	V	
V _F	Forward Voltage	I _F =50mA	2.3	2.7	3.2	V	
I _R	Reverse Current	V _R =5V	-	-	10	μA	

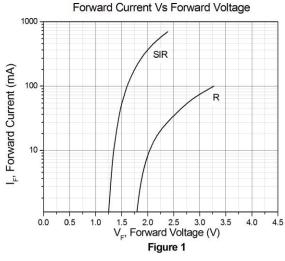
Notes:

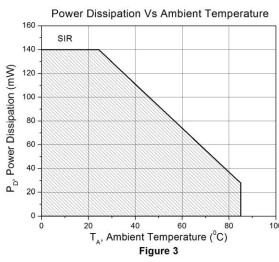
- 1. I_{FP} Conditions--Pulse Width \leq 100 μ s and Duty \leq 1%.
- 2. Soldering time≤ 5 seconds.

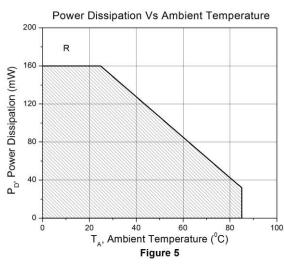


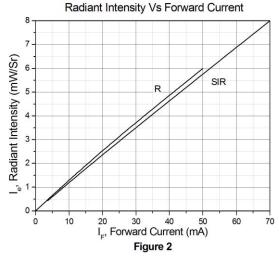


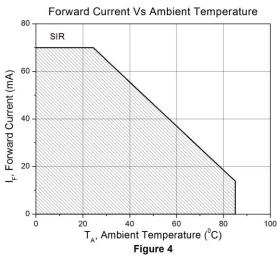
Typical Characteristic Curves

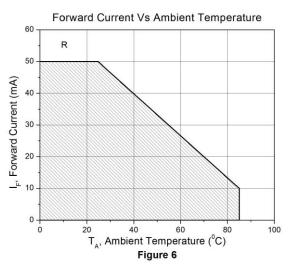








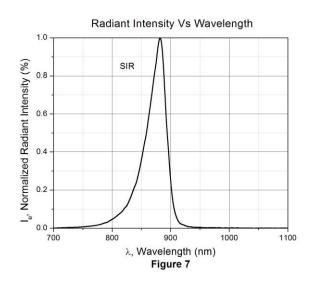


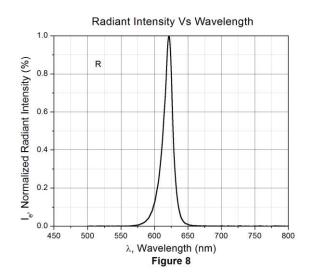




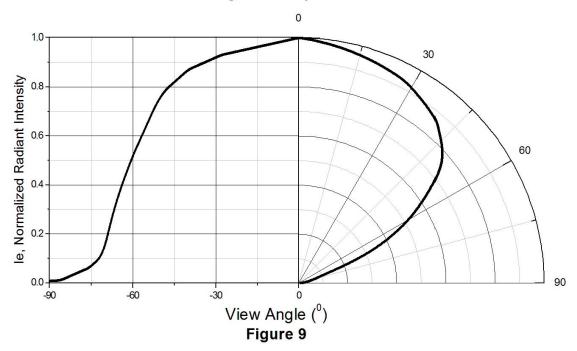


Typical Characteristic Curves



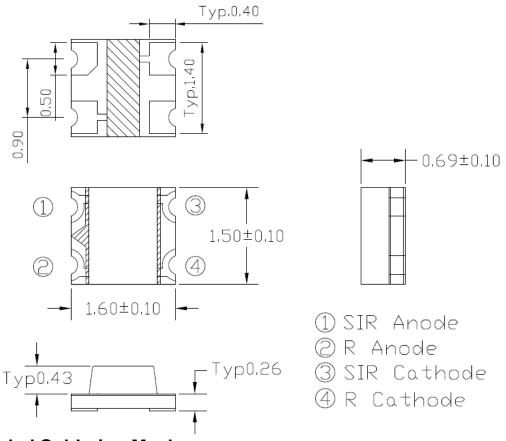


Angular Displacement

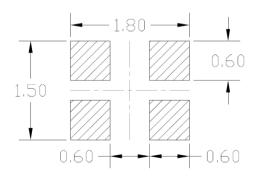


Dual Wavelength SMD Type Infrared Emitter

Package Dimension All dimensions are in mm, unless otherwise stated



Recommended Soldering Mask All dimensions are in mm, unless otherwise stated



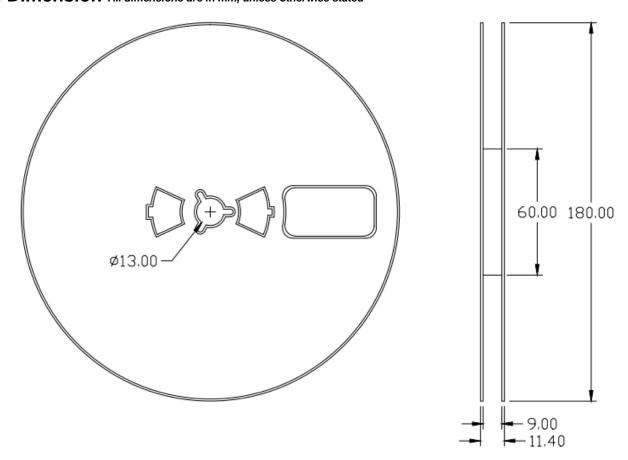
Ordering Information

Part Number	Description	Quantity
SRP1615X07-B20	Tape & Reel	4000 Pcs

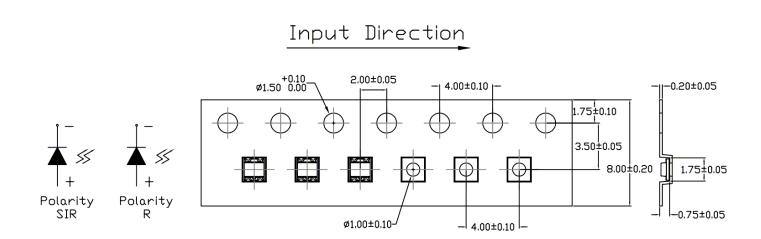




Reel Dimension All dimensions are in mm, unless otherwise stated



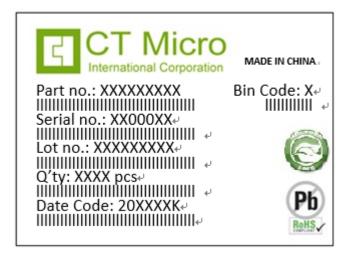
Tape Dimension All dimensions are in mm, unless otherwise stated







Label Form Specification



Part no: CTM Production Number Serial no: Production Number

Lot no: Lot number

Q'ty: Packing Quantity

Date Code: Manufacture Date

Bin Code: le Ranks

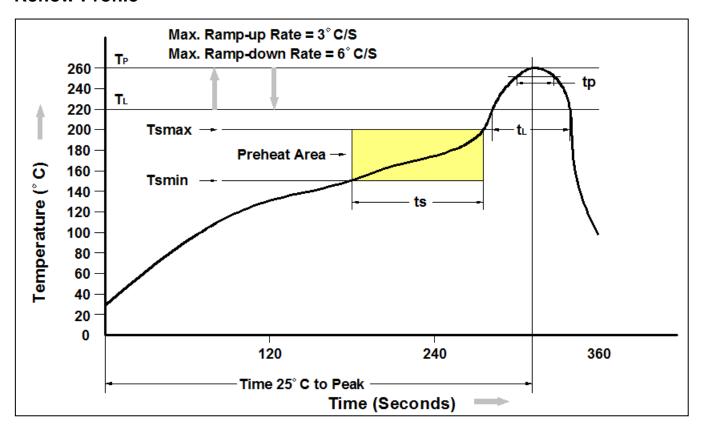
MADE IN CHINA: Production Place

Storage Condition

- 1. Do not open moisture proof bag before the products are ready to use.
- 2. The moisture barrier bag should be stored at 30°C and 90%R.H. max. before opening. Shelf life of non-opened bag is 12 months after the bag sealing date.
- 3. After opening the moisture barrier bag floor life is 168h at 30°C/60%RH. max. Unused LEDs should be resealed into moisture barrier bag. (Refer to J-STD-020 Standard)
- 4. If the moisture absorbent material has faded away or the LEDs have exceeded the storage time, baking treatment should be performed using the J-STD-033 Standard conditions.



Reflow Profile



Profile Feature	Pb-Free Assembly Profile
Temperature Min. (Tsmin)	150°C
Temperature Max. (Tsmax)	200°C
Time (ts) from (Tsmin to Tsmax)	60-120 seconds
Ramp-up Rate (t∟ to t⊳)	3°C/second max.
Liquidous Temperature (T _L)	217°C
Time (t _L) Maintained Above (T _L)	60 – 150 seconds
Peak Body Package Temperature	260°C +0°C / -5°C
Time (t _P) within 5°C of 260°C	30 seconds
Ramp-down Rate (T _P to T _L)	6°C/second max
Time 25°C to Peak Temperature	8 minutes max.



Dual Wavelength SMD Type Infrared Emitter

DISCLAIMER

CT MICRO RESERVES THE RIGHT TO MAKE CHANGES WITHOUT FURTHER NOTICE TO ANY PRODUCTS HEREIN TO IMPROVE RELIABILITY, FUNCTION OR DESIGN. CT MICRO DOES NOT ASSUME ANY LIABILITY ARISING OUT OF THE APPLICATION OR USE OF ANY PRODUCT OR CIRCUIT DESCRIBED HEREIN; NEITHER DOES IT CONVEY ANY LICENSE UNDER ITS PATENT RIGHTS, NOR THE RIGHTS OF OTHERS.

CT MICRO ARE NOT AUTHORIZED FOR LISE AS CRITICAL COMPONENTS IN LISE SURPORT DEVICES OR

CT MICRO ARE NOT AUTHORIZED FOR USE AS CRITICAL COMPONENTS IN LIFE SUPPORT DEVICES OR SYSTEMS WITHOUT EXPRESS WRITTEN APPROVAL OF CT MICRO INTERNATIONAL CORPORATION.

- Life support devices or systems are devices or systems which, (a) are intended for surgical implant into the body, or (b) support or sustain life, or (c) whose failure to perform when properly used in accordance with instruction for use provided in the labelling, can be reasonably expected to result in significant injury to the user.
- A critical component is any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.